

# Dual, 10-Bit *nano*DAC with 2 ppm/°C Reference, I<sup>2</sup>C Interface

Data Sheet AD5338R

#### **FEATURES**

Low drift 2.5 V reference: 2 ppm/°C typical Tiny package: 3 mm × 3 mm, 16-lead LFCSP

Total unadjusted error (TUE): ±0.1% of full-scale range (FSR)

maximum

Offset error: ±1.5 mV maximum Gain error: ±0.1% of FSR maximum

High drive capability: 20 mA, 0.5 V from supply rails

User selectable gain of 1 or 2 (GAIN pin)
Reset to zero scale or midscale (RSTSEL pin)

1.8 V logic compatibility Low glitch: 0.5 nV-sec

400 kHz I<sup>2</sup>C-compatible serial interface

Low power: 3.3 mW at 3 V 2.7 V to 5.5 V power supply

-40°C to +105°C temperature range

#### **APPLICATIONS**

Optical transceivers
Base station power amplifiers
Process controls (programmable logic controller [PLC] I/O cards)
Industrial automation
Data acquisition systems

#### **GENERAL DESCRIPTION**

The AD5338R, a member of the *nano*DAC\* family, is a low power, dual, 10-bit buffered voltage output digital-to-analog converter (DAC). The device includes a 2.5 V, 2 ppm/°C internal reference (enabled by default) and a gain select pin giving a full-scale output of 2.5 V (gain = 1) or 5 V (gain = 2). The AD5338R operates from a single 2.7 V to 5.5 V supply, is guaranteed monotonic by design, and exhibits less than 0.1% FSR gain error and 1.5 mV offset error performance. The device is available in a 3 mm  $\times$  3 mm LFCSP and a TSSOP package.

The AD5338R also incorporates a power-on reset circuit and a RSTSEL pin that ensures that the DAC outputs power up to zero scale or midscale and remain there until a valid write takes place. It contains a per channel power-down feature that reduces the current consumption of the device to 4  $\mu A$  at 3 V while in power-down mode.

The AD5338R uses a versatile 2-wire serial interface that operates at clock rates up to 400 kHz and includes a  $V_{\rm LOGIC}$  pin intended for 1.8 V/3 V/5 V logic.

#### **FUNCTIONAL BLOCK DIAGRAM**

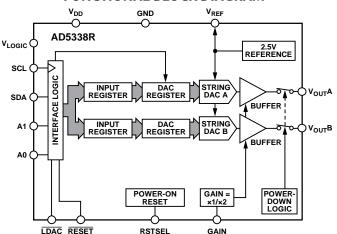


Figure 1.

Table 1. Related Devices

Interface	Reference	12-Bit	10-Bit
SPI	Internal	AD5687R	AD5313R <sup>1</sup>
	External	AD5687	AD5313 <sup>1</sup>
I <sup>2</sup> C	Internal	AD5697R	AD5338R1
	External		AD5338 <sup>1</sup>

<sup>&</sup>lt;sup>1</sup> The AD5338R and the AD5338 are not pin-to-pin or software compatible. The AD5313R and the AD5313 are not pin-to-pin or software compatible.

#### **PRODUCT HIGHLIGHTS**

1. Precision DC Performance.

TUE: ±0.1% of FSR maximum Offset error: ±1.5 mV maximum Gain error: ±0.1% of FSR maximum

2. Low Drift 2.5 V On-Chip Reference.

2 ppm/°C typical temperature coefficient 5 ppm/°C maximum temperature coefficient

3. Two Package Options.

 $3 \text{ mm} \times 3 \text{ mm}$ , 16-lead LFCSP 16-lead TSSOP

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# **TABLE OF CONTENTS**

Features
Applications1
Functional Block Diagram
General Description
Product Highlights
Revision History
Specifications3
AC Characteristics5
Timing Characteristics6
Absolute Maximum Ratings
ESD Caution7
Pin Configurations and Function Descriptions
Typical Performance Characteristics9
Terminology
Theory of Operation
Digital-to-Analog Converter17
Transfer Function
DAC Architecture
Serial Interface
Write and Update Commands18
REVISION HISTORY
5/2017—Rev. 0 to Rev. A
Changes to Features Section
Change to Table 1 Summary
Changes to Table 35
Changes to Table 4 Summary
Changes to Table 5
Changes to V <sub>LOGIC</sub> Pin Description and RESET Pin Description,
Table 6
Changes to Figure 13 to Figure 16
Changes to Figure 17 to Figure 2111
Changes to Figure 27
Changes to Figure 34
Changes to Figure 35
Changes to Figure 44
Changes to Hardware Reset (RESET) Section, Long-Term
Temperature Drift Section, and Figure 48
Changes to Ordering Guide

Serial Operation
Write Operation
Read Operation
Multiple DAC Readback Sequence
Power-Down Operation21
Load DAC (Hardware LDAC Pin)
LDAC Mask Register
Hardware Reset (RESET)
Reset Select Pin (RSTSEL)
Internal Reference Setup
Solder Heat Reflow23
Long-Term Temperature Drift
Thermal Hysteresis
Applications Information
Microprocessor Interfacing
ADSP-BF531 Interface
Layout Guidelines
Galvanically Isolated Interface
Outline Dimensions
Ordering Guide

#### 2/2013—Revision 0: Initial Version

# **SPECIFICATIONS**

 $V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}; 1.62 \text{ V} \leq V_{LOGIC} \leq 5.5 \text{ V}; \text{ and all specifications } T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. } R_L = 2 \text{ k}\Omega; \text{ and } C_L = 200 \text{ pF.}$ 

Table 2.

Parameter	Min	Тур	Max	Unit	Test Conditions/Comments
STATIC PERFORMANCE <sup>1</sup>					
Resolution	10			Bits	
Relative Accuracy		±0.12	±0.5	LSB	
Differential Nonlinearity			±0.5	LSB	Guaranteed monotonic by design
Zero-Code Error		0.4	1.5	mV	All 0s loaded to DAC register
Offset Error		+0.1	±1.5	mV	_
Full-Scale Error		+0.01	±0.1	% of FSR	All 1s loaded to DAC register
Gain Error		±0.02	±0.1	% of FSR	_
Total Unadjusted Error		±0.01	±0.1	% of FSR	External reference; gain = 2; TSSOP
			±0.2	% of FSR	Internal reference; gain = 1; TSSOP
Offset Error Drift <sup>2</sup>		±1		μV/°C	
Gain Temperature Coefficient <sup>2</sup>		±1		ppm	Of FSR/°C
DC Power Supply Rejection Ratio <sup>2</sup>		0.15		mV/V	DAC code = midscale; $V_{DD} = 5 V \pm 10\%$
DC Crosstalk <sup>2</sup>					
		±2		μV	Due to single channel, full-scale output change
		±3		μV/mA	Due to load current change
		±2		μV	Due to powering down (per channel)
OUTPUT CHARACTERISTICS <sup>2</sup>					
Output Voltage Range	0		$V_{REF}$	٧	Gain = 1
	0		$2 \times V_{REF}$	٧	Gain = 2, see Figure 25
Capacitive Load Stability		2		nF	R <sub>L</sub> = ∞
,		10		nF	$R_L = 1 \text{ k}\Omega$
Resistive Load <sup>3</sup>	1			kΩ	
Load Regulation		80		μV/mA	5 V ± 10%, DAC code = midscale;
3				'	$-30 \text{ mA} \le I_{\text{OUT}} \le +30 \text{ mA}$
		80		μV/mA	$3 V \pm 10\%$ , DAC code = midscale;
					$-20 \text{ mA} \le I_{\text{OUT}} \le +20 \text{ mA}$
Short-Circuit Current⁴		40		mA	
Load Impedance at Rails <sup>5</sup>		25		Ω	See Figure 25
Power-Up Time		2.5		μs	Coming out of power-down mode; $V_{DD} = 5 \text{ V}$
REFERENCE OUTPUT					
Output Voltage <sup>6</sup>	2.4975		2.5025	V	At ambient
Reference Temperature Coefficient 7,8		2	5	ppm/°C	See the Terminology section
Output Impedance <sup>2</sup>		0.04		Ω	
Output Voltage Noise <sup>2</sup>		12		μV p-p	0.1 Hz to 10 Hz
Output Voltage Noise Density <sup>2</sup>		240		nV/√Hz	At ambient; $f = 10 \text{ kHz}$ , $C_L = 10 \text{ nF}$
Load Regulation Sourcing <sup>2</sup>		20		μV/mA	At ambient
Load Regulation Sinking <sup>2</sup>		40		μV/mA	At ambient
Output Current Load Capability <sup>2</sup>		±5		mA	$V_{DD} \ge 3 V$
Line Regulation <sup>2</sup>		100		μV/V	At ambient
Long-Term Stability/Drift <sup>2</sup>		12		ppm	After 1000 hours at 125°C
Thermal Hysteresis <sup>2</sup>		125		ppm	First cycle
		25		ppm	Additional cycles
LOGIC INPUTS <sup>2</sup>					
Input Current			±2	μΑ	Per pin
Input Low Voltage, V <sub>INL</sub>			$0.3 \times V_{\text{LOGIC}}$	V	
Input High Voltage, V <sub>INH</sub>	$0.7 \times V_{LOGIC}$			V	
Pin Capacitance		2		pF	

Parameter	Min	Тур	Max	Unit	Test Conditions/Comments
LOGIC OUTPUTS (SDA) <sup>2</sup>					
Output Low Voltage, Vol			0.4	V	I <sub>SINK</sub> = 3 mA
Floating State Output Capacitance		4		pF	
POWER REQUIREMENTS					
$V_{LOGIC}$	1.8		5.5	V	
ILOGIC			3	μΑ	
$V_{DD}$	2.7		5.5	V	Gain = 1
	$V_{REF} + 1.5$		5.5	V	Gain = 2
$I_{DD}$					$V_{IH} = V_{DD}$ , $V_{IL} = GND$ , $V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}$
Normal Mode <sup>9</sup>		0.59	0.7	mA	Internal reference off
		1.1	1.3	mA	Internal reference on, at full scale
All Power-Down Modes <sup>10</sup>		1	4	μΑ	-40°C to +85°C
			6	μΑ	-40°C to +105°C

<sup>&</sup>lt;sup>1</sup> DC specifications tested with the outputs unloaded, unless otherwise noted. Upper dead band = 10 mV and exists only when  $V_{REF} = V_{DD}$  with gain = 1 or when  $V_{REF}/2 = V_{DD}$  with gain = 2. Linearity calculated using a reduced code range of 4 to 1020.

<sup>&</sup>lt;sup>2</sup> Guaranteed by design and characterization; not production tested.

<sup>&</sup>lt;sup>3</sup> Channel A can have an output current of up to 30 mA. Similarly, Channel B can have an output current of up to 30 mA up to a junction temperature of 100°C.

<sup>&</sup>lt;sup>4</sup>V<sub>DD</sub> = 5 V. The device includes current limiting that is intended to protect the device during temporary overload conditions. Junction temperature can be exceeded during current limit. Operation above the specified maximum operation junction temperature may impair device reliability.

 $<sup>^5</sup>$  When drawing a load current at either rail, the output voltage headroom with respect to that rail is limited by the 25 Ω typical channel resistance of the output device. For example, when sinking 1 mA, the minimum output voltage = 25 Ω × 1 mA = 25 mV (see Figure 25).

<sup>6</sup> Initial accuracy presolder reflow is ±750 μV; output voltage includes the effects of preconditioning drift. See the Internal Reference Setup section.

 $<sup>^{7}</sup>$  Reference is trimmed and tested at two temperatures and is characterized from  $-40^{\circ}$ C to  $+105^{\circ}$ C.

<sup>&</sup>lt;sup>8</sup> Reference temperature coefficient is calculated as per the box method. See the Terminology section for further information.

<sup>&</sup>lt;sup>9</sup> Interface inactive. Both DACs active. DAC outputs unloaded.

<sup>&</sup>lt;sup>10</sup> Both DACs powered down.

#### **AC CHARACTERISTICS**

 $V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}; R_L = 2 \text{ k}\Omega \text{ to GND}; C_L = 200 \text{ pF to GND}; 1.62 \text{ V} \leq V_{LOGIC} \leq 5.5 \text{ V}; all specifications } T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise } T_{MAX} = 2 \text{ k}\Omega \text{ to GND}; C_L = 200 \text{ pF to GND}; 1.62 \text{ V} \leq V_{LOGIC} \leq 5.5 \text{ V}; all specifications } T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise } T_{MAX} = 2 \text{ k}\Omega \text{ to GND}; C_L = 200 \text{ pF to GND}; 1.62 \text{ V} \leq V_{LOGIC} \leq 5.5 \text{ V}; all specifications } T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise } T_{MAX} = 2 \text{ k}\Omega \text{ to GND}; C_L = 200 \text{ pF to GND}; C_L$ noted. Guaranteed by design and characterization; not production tested.

Table 3.

Parameter <sup>1</sup>	Min	Тур	Max	Unit	Test Conditions/Comments <sup>2</sup>
Output Voltage Settling Time		5	7	μs	1/4 to 3/4 scale settling to ±2 LSB
Slew Rate		8.0		V/µs	
Digital-to-Analog Glitch Impulse		0.5		nV-sec	1 LSB change around major carry
Digital Feedthrough		0.13		nV-sec	
Digital Crosstalk		0.1		nV-sec	
Analog Crosstalk		0.2		nV-sec	
DAC-to-DAC Crosstalk		0.3		nV-sec	
Total Harmonic Distortion (THD) <sup>3</sup>		-80		dB	At ambient, bandwidth = 20 kHz, $V_{DD}$ = 5 V, $f_{OUT}$ = 1 kHz
Output Noise Spectral Density		300		nV/√Hz	DAC code = midscale, 10 kHz; gain = 2, internal reference enabled
Output Noise		6		μV p-p	0.1 Hz to 10 Hz
Signal-to-Noise Ratio (SNR)		90		dB	At ambient, bandwidth = 20 kHz, $V_{DD}$ = 5 V, $f_{OUT}$ = 1 kHz
Spurious-Free Dynamic Range (SFDR)		83		dB	At ambient, bandwidth = 20 kHz, $V_{DD}$ = 5 V, $f_{OUT}$ = 1 kHz
Signal-to-Noise-and-Distortion Ratio (SINAD)		80		dB	At ambient, bandwidth = 20 kHz, $V_{DD}$ = 5 V, $f_{OUT}$ = 1 kHz

 $<sup>^1</sup>$  See the Terminology section.  $^2$  Temperature range is  $-40^{\circ}\text{C}$  to +105°C, typical at 25°C.

<sup>&</sup>lt;sup>3</sup> Digitally generated sine wave at 1 kHz.

#### **TIMING CHARACTERISTICS**

 $V_{DD} = 2.5 \text{ V}$  to 5.5 V; 1.62 V  $\leq V_{LOGIC} \leq 5.5 \text{ V}$ ; all specifications  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. See Figure 2.

Table 4.

Parameter <sup>1</sup>	Min	Max	Unit	Test Conditions/Comments
t <sub>1</sub>	2.5		μs	SCL cycle time
$t_2$	0.6		μs	SCL high time, t <sub>HIGH</sub>
t <sub>3</sub>	1.3		μs	SCL low time, t <sub>LOW</sub>
$t_4$	0.6		μs	Start/repeated start condition hold time, t <sub>HD,STA</sub>
<b>t</b> <sub>5</sub>	100		ns	Data setup time, t <sub>SU,DAT</sub>
$t_6^2$	0	0.9	μs	Data hold time, t <sub>HD,DAT</sub>
t <sub>7</sub>	0.6		μs	Setup time for repeated start, t <sub>SU,STA</sub>
t <sub>8</sub>	0.6		μs	Stop condition setup time, t <sub>SU,STO</sub>
<b>t</b> 9	1.3		μs	Bus free time between a stop and a start condition, t <sub>BUF</sub>
t <sub>10</sub>	0	300	ns	Rise time of SCL and SDA when receiving, $t_{\mbox{\scriptsize R}}$
t <sub>11</sub>	$20 + 0.1C_{B}^{3}$	300	ns	Fall time of SDA and SCL when transmitting/receiving, t <sub>F</sub>
t <sub>12</sub>	20		ns	LDAC pulse width
t <sub>13</sub>	400		ns	SCL rising edge to LDAC rising edge
$C_B^3$		400	pF	Capacitive load for each bus line

<sup>&</sup>lt;sup>1</sup> Guaranteed by design and characterization; not production tested.

 $<sup>^3</sup>$  C<sub>B</sub> is the total capacitance of one bus line in pF.  $t_R$  and  $t_F$  measured between 0.3  $V_{DD}$  and 0.7  $V_{DD}$ .

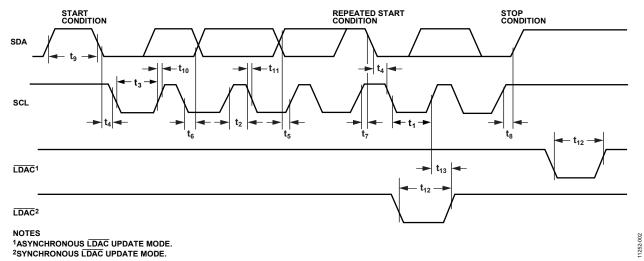


Figure 2. 2-Wire Serial Interface Timing Diagram

<sup>&</sup>lt;sup>2</sup> A master device must provide a hold time of at least 300 ns for the SDA signal (referred to the V<sub>H</sub> minimum of the SCL signal) to bridge the undefined region of the falling edge of the SCL.

### **ABSOLUTE MAXIMUM RATINGS**

 $T_A = 25$ °C, unless otherwise noted.

Table 5.

Parameter	Rating
V <sub>DD</sub> to GND	−0.3 V to +7 V
V <sub>LOGIC</sub> to GND	−0.3 V to +7 V
Vout to GND	$-0.3 \text{ V to V}_{DD} + 0.3 \text{ V}$
V <sub>REF</sub> to GND	$-0.3 \text{ V to V}_{DD} + 0.3 \text{ V}$
Digital Input Voltage to GND <sup>1</sup>	$-0.3 \text{ V to V}_{LOGIC} + 0.3 \text{ V}$
SDA and SCL to GND	−0.3 V to +7 V
Operating Temperature Range	−40°C to +105°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	125°C
16-Lead TSSOP, θ <sub>JA</sub> Thermal Impedance, 0 Airflow (4-Layer Board)	112.6°C/W
16-Lead LFCSP, θ <sub>JA</sub> Thermal Impedance, 0 Airflow (4-Layer Board)	70°C/W
Reflow Soldering Peak Temperature, Pb Free (J-STD-020)	260°C

<sup>&</sup>lt;sup>1</sup> Excluding SDA and SCL.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

#### **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

# PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

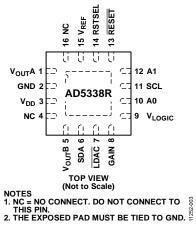


Figure 3. 16-Lead LFCSP Pin Configuration

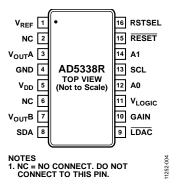


Figure 4. 16-Lead TSSOP Pin Configuration

**Table 6. Pin Function Descriptions** 

	Pin No.		
LFCSP	TSSOP	Mnemonic	Description
1	3	V <sub>OUT</sub> A	Analog Output Voltage from DAC A. The output amplifier has rail-to-rail operation.
16	2	NC	No Connect. Do not connect to this pin.
2	4	GND	Ground Reference Point for All Circuitry on the Part.
3	5	V <sub>DD</sub>	Power Supply Input. This part can be operated from 2.7 V to 5.5 V. Decouple the supply with a 10 µF capacitor in parallel with a 0.1 µF capacitor to GND.
4	6	NC	No Connect. Do not connect to this pin.
5	7	V <sub>OUT</sub> B	Analog Output Voltage from DAC B. The output amplifier has rail-to-rail operation.
6	8	SDA	Serial Data Input. This pin is used in conjunction with the SCL line to clock data into or out of the 24-bit input shift register. SDA is a bidirectional, open-drain data line that should be pulled to the supply with an external pull-up resistor.
7	9	LDAC	LDAC can be operated in two modes, asynchronous and synchronous. Pulsing this pin low allows any or all DAC registers to be updated if the input registers have new data. This allows both DAC outputs to simultaneously update. This pin can also be tied permanently low.
8	10	GAIN	Gain Select. When this pin is tied to GND, both DAC outputs have a span from 0 V to $V_{REF}$ . If this pin is tied to $V_{LOGIC}$ , both DACs output a span of 0 V to 2 $\times$ $V_{REF}$ .
9	11	$V_{LOGIC}$	Digital Power Supply. Voltage ranges from 1.62 V to 5.5 V.
10	12	A0	Address Input. Sets the first LSB of the 7-bit slave address.
11	13	SCL	Serial Clock Line. This is used in conjunction with the SDA line to clock data into or out of the 24-bit input register.
12	14	A1	Address Input. Sets the second LSB of the 7-bit slave address.
13	15	RESET	Asynchronous Reset Input. The RESET input is falling edge sensitive. When RESET is low, all LDAC pulses are ignored. When RESET is activated, the input register and the DAC register are updated with zero scale or midscale, depending on the state of the RSTSEL pin. If the pin is forced low at power-up, the POR circuit does not initialize correctly until the pin is released.
14	16	RSTSEL	Power-On Reset Select. Tying this pin to GND powers up both DACs to zero scale. Tying this pin to $V_{\text{LOGIC}}$ powers up both DACs to midscale.
15	1	V <sub>REF</sub>	Reference Voltage. The AD5338R has a common reference pin. When using the internal reference, this is the reference output pin. When using an external reference, this is the reference input pin. The default for this pin is as a reference output.
	Not applicable	EPAD	Exposed Pad. The exposed pad must be tied to GND.

# TYPICAL PERFORMANCE CHARACTERISTICS

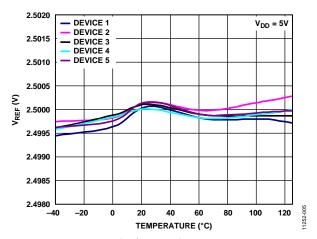


Figure 5. Internal Reference Voltage vs. Temperature

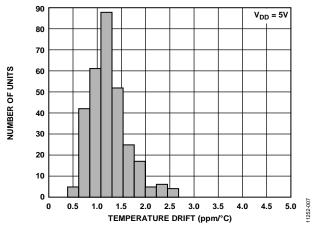


Figure 6. Reference Output Temperature Drift Histogram

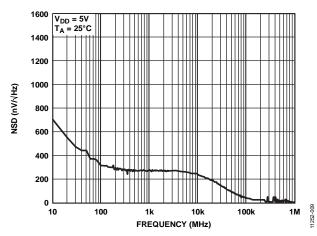


Figure 7. Internal Reference Noise Spectral Density vs. Frequency

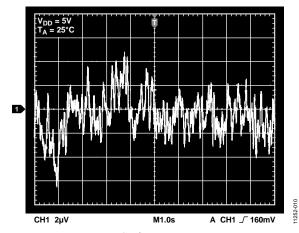


Figure 8. Internal Reference Noise, 0.1 Hz to 10 Hz

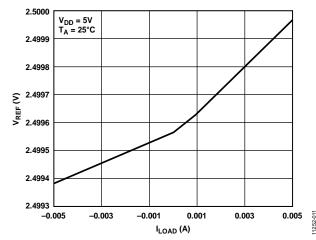


Figure 9. Internal Reference Voltage vs. Load Current

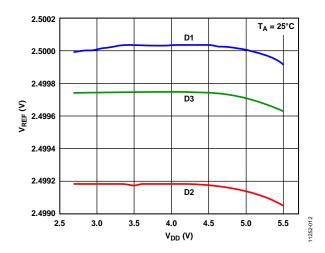


Figure 10. Internal Reference Voltage vs. Supply Voltage

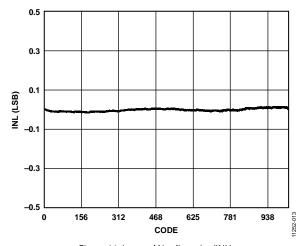


Figure 11. Integral Nonlinearity (INL)

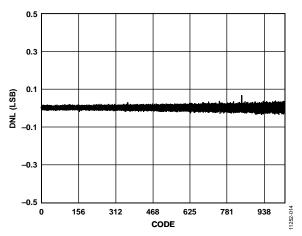


Figure 12. Differential Nonlinearity (DNL)

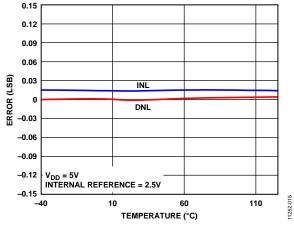


Figure 13. INL Error and DNL Error vs. Temperature

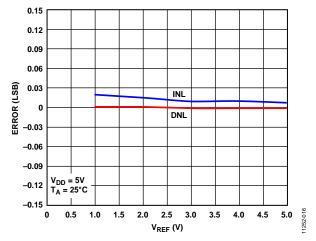


Figure 14. INL Error and DNL Error vs. V<sub>REF</sub>

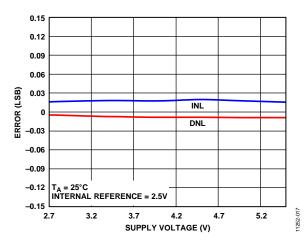


Figure 15. INL Error and DNL Error vs. Supply Voltage

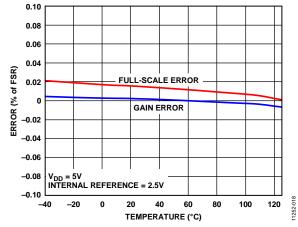


Figure 16. Gain Error and Full-Scale Error vs. Temperature

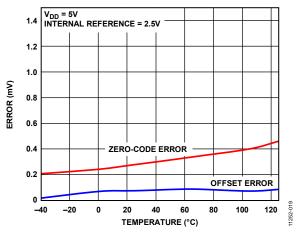


Figure 17. Zero-Code Error and Offset Error vs. Temperature

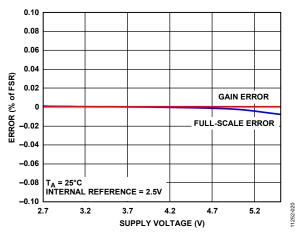


Figure 18. Gain Error and Full-Scale Error vs. Supply Voltage

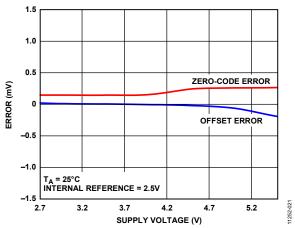


Figure 19. Zero-Code Error and Offset Error vs. Supply Voltage

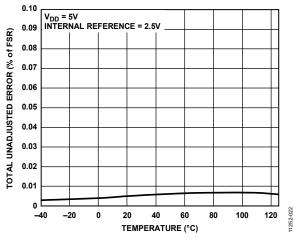


Figure 20. Total Unadjusted Error vs. Temperature

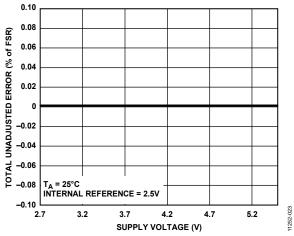


Figure 21. Total Unadjusted Error vs. Supply Voltage, Gain = 1

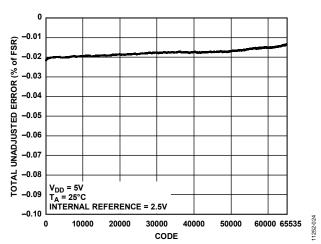


Figure 22. Total Unadjusted Error vs. Code

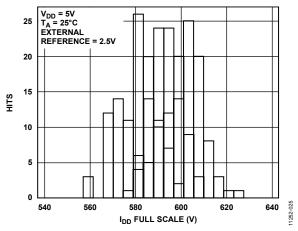


Figure 23. IDD Histogram with External Reference

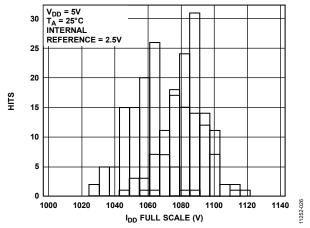


Figure 24.  $I_{DD}$  Histogram with Internal Reference,  $V_{REFOUT} = 2.5 V$ , Gain = 2

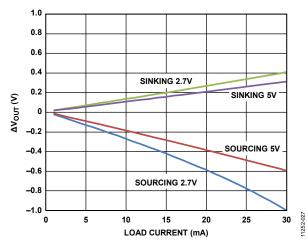


Figure 25. Headroom/Footroom vs. Load Current

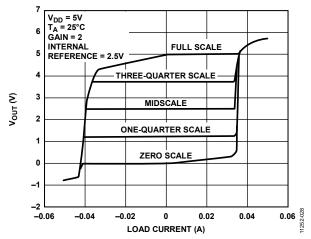


Figure 26. Source and Sink Capability at  $V_{DD} = 5 V$ 

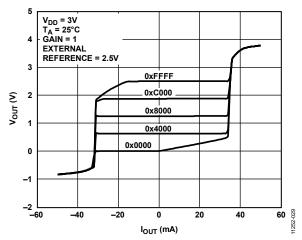


Figure 27. Source and Sink Capability at  $V_{DD} = 3 V$ 

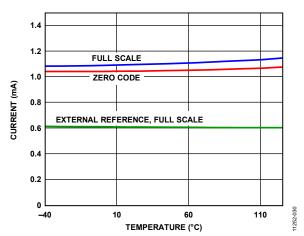


Figure 28. Supply Current vs. Temperature

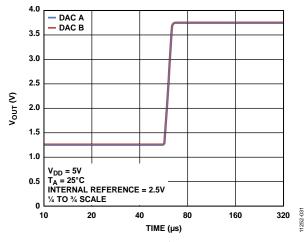


Figure 29. Settling Time

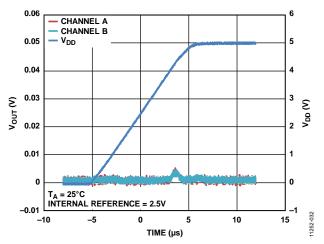


Figure 30. Power-On Reset to 0 V

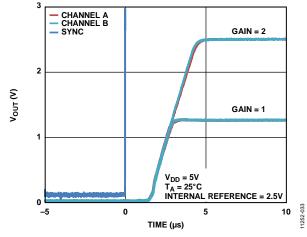


Figure 31. Exiting Power-Down to Midscale

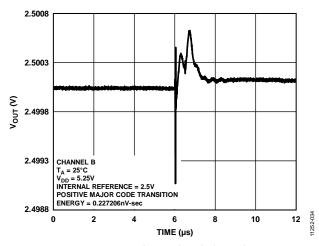


Figure 32. Digital-to-Analog Glitch Impulse

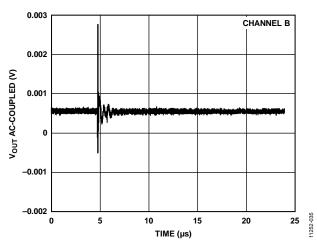


Figure 33. Analog Crosstalk, Channel A

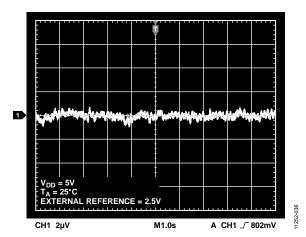


Figure 34. 0.1 Hz to 10 Hz Output Noise Plot, External Reference

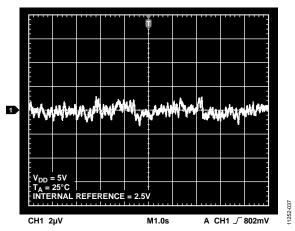


Figure 35. 0.1 Hz to 10 Hz Output Noise Plot, 2.5 V Internal Reference

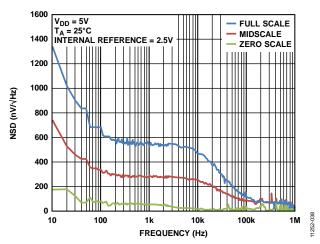


Figure 36. Noise Spectral Density

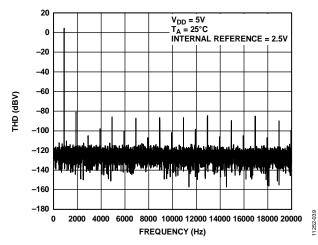


Figure 37. Total Harmonic Distortion at 1 kHz

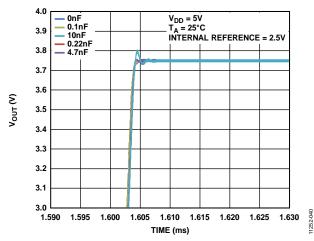


Figure 38. Settling Time vs. Capacitive Load

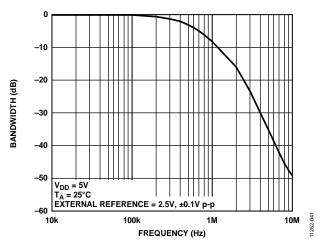


Figure 39. Multiplying Bandwidth, External Reference = 2.5 V,  $\pm 0.1$  V p-p, 10 kHz to 10 MHz

#### TERMINOLOGY

#### Relative Accuracy or Integral Nonlinearity (INL)

For the DAC, relative accuracy or integral nonlinearity is a measurement of the maximum deviation, in LSBs, from a straight line passing through the endpoints of the DAC transfer function. A typical INL vs. code plot is shown in Figure 11.

#### Differential Nonlinearity (DNL)

Differential nonlinearity is the difference between the measured change and the ideal 1 LSB change between any two adjacent codes. A specified differential nonlinearity of  $\pm 1$  LSB maximum ensures monotonicity. This DAC is guaranteed monotonic by design. A typical DNL vs. code plot can be seen in Figure 12.

#### **Zero-Code Error**

Zero-code error is a measurement of the output error when zero code (0x0000) is loaded to the DAC register. Ideally, the output should be 0 V. The zero-code error is always positive in the AD5338R because the output of the DAC cannot go less than 0 V due to a combination of the offset errors in the DAC and the output amplifier. Zero-code error is expressed in mV. A plot of the zero-code error vs. the temperature can be seen in Figure 17.

#### **Full-Scale Error**

Full-scale error is a measurement of the output error when full-scale code is loaded to the DAC register. Ideally, the output should be  $V_{\rm DD}-1$  LSB. Full-scale error is expressed in percent of full-scale range (% of FSR). A plot of the full-scale error vs. the temperature can be seen in Figure 16.

#### **Gain Error**

This is a measure of the span error of the DAC. It is the deviation in slope of the DAC transfer characteristic from the ideal expressed as % of FSR.

#### Offset Error Drift

This is a measurement of the change in offset error with a change in temperature. It is expressed in  $\mu V$ /°C.

#### **Gain Temperature Coefficient**

This is a measurement of the change in gain error with changes in temperature. It is expressed in ppm of FSR/°C.

#### **Offset Error**

Offset error is a measure of the difference between  $V_{\text{OUT}}$  (actual) and  $V_{\text{OUT}}$  (ideal) expressed in mV in the linear region of the transfer function. Offset error is measured on the AD5338R with Code 8 loaded in the DAC register. It can be negative or positive.

#### DC Power Supply Rejection Ratio (PSRR)

This indicates how the output of the DAC is affected by changes in the supply voltage. PSRR is the ratio of the change in  $V_{\text{OUT}}$  to a change in  $V_{\text{DD}}$  for full-scale output of the DAC. It is measured in mV/V.  $V_{\text{REF}}$  is held at 2 V, and  $V_{\text{DD}}$  is varied by  $\pm 10\%$ .

#### **Output Voltage Settling Time**

Output voltage settling time is the time it takes for the output of a DAC to settle to a specified level for a ¼ to ¾ full-scale input change.

#### Digital-to-Analog Glitch Impulse

Digital-to-analog glitch impulse is the impulse injected into the analog output when the input code in the DAC register changes state. It is normally specified as the area of the glitch in nV-sec, and is measured when the digital input code is changed by 1 LSB at the major carry transition, 0x7FFF to 0x8000, (see Figure 32).

#### Digital Feedthrough

Digital feedthrough is a measure of the impulse injected into the analog output of the DAC from the digital inputs of the DAC, but is measured when the DAC output is not updated. It is specified in nV-sec, and measured with a full-scale code change on the data bus, that is, from all 0s to all 1s and vice versa.

#### Reference Feedthrough

Reference feedthrough is the ratio of the amplitude of the signal at the DAC output to the reference input when the DAC output is not being updated. It is expressed in dB.

#### **Noise Spectral Density**

This is a measurement of the internally generated random noise. Random noise is characterized as a spectral density ( $nV/\sqrt{Hz}$ ). It is measured by loading the DAC to midscale and measuring noise at the output. It is measured in  $nV/\sqrt{Hz}$ . A plot of noise spectral density is shown in Figure 36.

#### **DC Crosstalk**

DC crosstalk is the dc change in the output level of one DAC in response to a change in the output of another DAC. It is measured with a full-scale output change on one DAC (or soft power-down and power-up) while monitoring another DAC kept at midscale. It is expressed in  $\mu V$ .

DC crosstalk due to load current change is a measure of the impact that a change in load current on one DAC has to another DAC kept at midscale. It is expressed in  $\mu V/mA$ .

#### **Digital Crosstalk**

This is the glitch impulse transferred to the output of one DAC at midscale in response to a full-scale code change (all 0s to all 1s and vice versa) in the input register of another DAC. It is measured in standalone mode and is expressed in nV-sec.

#### **Analog Crosstalk**

This is the glitch impulse transferred to the output of one DAC due to a change in the output of another DAC. It is measured by loading one of the input registers with a full-scale code change (all 0s to all 1s and vice versa). Then execute a software LDAC and monitor the output of the DAC whose digital code was not changed. The area of the glitch is expressed in nV-sec.

#### **DAC-to-DAC Crosstalk**

This is the glitch impulse transferred to the output of one DAC due to a digital code change and subsequent analog output change of another DAC. It is measured by loading the attack channel with a full-scale code change (all 0s to all 1s and vice versa), using the write to and update commands while monitoring the output of the victim channel that is at midscale. The energy of the glitch is expressed in nV-sec.

#### **Multiplying Bandwidth**

The amplifiers within the DAC have a finite bandwidth. The multiplying bandwidth is a measure of this. A sine wave on the reference (with full-scale code loaded to the DAC) appears on the output. The multiplying bandwidth is the frequency at which the output amplitude falls to 3 dB below the input.

#### **Total Harmonic Distortion (THD)**

THD is the difference between an ideal sine wave and its attenuated version using the DAC. The sine wave is used as the reference for the DAC, and the THD is a measurement of the harmonics present on the DAC output. It is measured in dB.

#### Voltage Reference Temperature Coefficient (TC)

Voltage reference TC is a measure of the change in the reference output voltage with a change in temperature. The reference TC is calculated using the box method, which defines the TC as the maximum change in the reference output over a given temperature range expressed in ppm/°C as follows;

$$TC = \left[ \frac{V_{REFmax} - V_{REFmin}}{V_{REFnom} \times TempRange} \right] \times 10^{6}$$

where:

 $V_{REFmax}$  is the maximum reference output measured over the total temperature range.

 $V_{REFmin}$  is the minimum reference output measured over the total temperature range.

 $V_{REFnom}$  is the nominal reference output voltage, 2.5 V. *TempRange* is the specified temperature range of  $-40^{\circ}$ C to  $+105^{\circ}$ C.

# THEORY OF OPERATION DIGITAL-TO-ANALOG CONVERTER

The AD5338R is a dual, 10-bit, serial input, voltage output DAC with an internal reference. The part operates from supply voltages of 2.7 V to 5.5 V. Data is written to the AD5338R in a 24-bit word format via a 2-wire serial interface. The AD5338R incorporates a power-on reset circuit to ensure that the DAC output powers up to a known output state. The device also has a software power-down mode that reduces the typical current consumption to 4  $\mu A$ .

#### TRANSFER FUNCTION

The internal reference is on by default. To use an external reference, only a nonreference option is available. Because the input coding to the DAC is straight binary, the ideal output voltage when using an external reference is given by

$$V_{OUT} = V_{REF} \times Gain \left[ \frac{D}{2^N} \right]$$

where:

*Gain* is the gain of the output amplifier and is set to 1 by default. This can be set to  $\times 1$  or  $\times 2$  using the gain select pin. When this pin is tied to GND, both DAC outputs have a span from 0 V to  $V_{REF}$ . If this pin is tied to  $V_{LOGIC}$ , both DACs output a span of 0 V to  $2 \times V_{REF}$ .

*D* is the decimal equivalent of the binary code that is loaded to the DAC register as 0 to 1,023 for the 10-bit device.

N is the DAC resolution.

#### **DAC ARCHITECTURE**

The DAC architecture consists of a string DAC followed by an output amplifier. Figure 40 shows a block diagram of the DAC architecture.

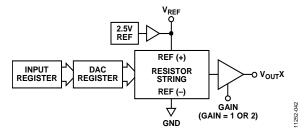


Figure 40. Single DAC Channel Architecture Block Diagram

The resistor string structure is shown in Figure 41. It is a string of resistors, each of Value R. The code loaded to the DAC register determines the node on the string where the voltage is to be tapped off and fed into the output amplifier. The voltage is tapped off by closing one of the switches connecting the string to the amplifier. Because it is a string of resistors, it is guaranteed monotonic.

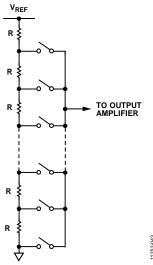


Figure 41. Resistor String Structure

#### Internal Reference

The AD5338R on-chip reference is on at power-up but can be disabled via a write to a control register. See the Internal Reference Setup section for details.

The AD5338R has a 2.5 V, 2 ppm/ $^{\circ}$ C reference, giving a full-scale output of 2.5 V or 5 V depending on the state of the GAIN pin. The internal reference associated with the device is available at the V<sub>REF</sub> pin. This buffered reference is capable of driving external loads of up to 10 mA.

#### **Output Amplifiers**

The output buffer amplifier can generate rail-to-rail voltages on its output, which gives an output range of 0 V to  $V_{\rm DD}$ . The actual range depends on the value of  $V_{\rm REF}$ , the GAIN pin, the offset error, and the gain error. The GAIN pin selects the gain of the output.

- If GAIN is tied to GND, both outputs have a gain of 1, and the output range is 0 V to  $V_{\text{REF}}$ .
- If GAIN is tied to  $V_{\text{LOGIC}}$ , both outputs have a gain of 2, and the output range is 0 V to 2 ×  $V_{\text{REF}}$ .

These amplifiers are capable of driving a load of 1 k $\Omega$  in parallel with 2 nF to GND. The slew rate is 0.8 V/ $\mu$ s with a  $\frac{1}{4}$  to  $\frac{3}{4}$  scale settling time of 5  $\mu$ s.

#### **SERIAL INTERFACE**

The AD5338R has a 2-wire I<sup>2</sup>C-compatible serial interface (refer to I<sup>2</sup>C-Bus Specification, Version 2.1, January 2000, available from Philips Semiconductor). See Figure 2 for a timing diagram of a typical write sequence. The AD5338R can be connected to an I<sup>2</sup>C bus as a slave device, under the control of a master device. The AD5338R can support standard (100 kHz) and fast (400 kHz) data transfer modes. Support is not provided for 10-bit addressing and general call addressing.

#### **Input Shift Register**

The input shift register of the AD5338R is 24 bits wide. Data is loaded into the device as a 24-bit word under the control of a serial clock input, SCL. The first eight MSBs make up the command byte. The first four bits are the command bits (C3, C2, C1, and C0) that control the mode of operation of the device (see Table 7). The last four bits of the first byte are the address bits (DAC B, 0, 0, and DAC A, see Table 8).

The data-word comprises 10-bit input code, followed by six don't care bits for the AD5338R. These data bits are transferred to the input register on the 24 falling edges of SCL.

Commands can be executed on the individual DAC channels or on both DACs, depending on the address bits selected.

**Table 7. Command Definitions** 

	Comi	mand		
C3	C2	<b>C</b> 1	CO	Description
0	0	0	0	No operation
0	0	0	1	Write to Input Register n (dependent on LDAC)
0	0	1	0	Update DAC Register n with contents of Input Register n
0	0	1	1	Write to and update DAC Channel n
0	1	0	0	Power down/power up DAC
0	1	0	1	Hardware LDAC mask register
0	1	1	0	Software reset (power-on reset)
0	1	1	1	Internal reference setup register
1	0	0	0	Reserved
				Reserved
1	1	1	1	Reserved

**Table 8. Address Commands** 

	Selected D	AC Chann	el	
DAC B	DB18	DB17	DAC A	Description
0	0	0	1	DAC A
1	0	0	0	DAC B
1	0	0	1	DAC A and DAC B

#### WRITE AND UPDATE COMMANDS

#### Write to Input Register n (Dependent on LDAC)

Command 0001 allows the user to write to the dedicated input register of each DAC individually. When  $\overline{LDAC}$  is low, the input register is transparent (if not controlled by the  $\overline{LDAC}$  mask register).

#### Update DAC Register n with Contents of Input Register n

Command 0010 loads the DAC registers/outputs with the contents of the input registers selected and updates the DAC outputs directly.

#### Write to and Update DAC Channel n (Independent of LDAC)

Command 0011 allows the user to write to the DAC registers and update the DAC outputs directly.

DB23	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
С3	C2	C1	C0	DAC B	0	0	DAC A	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	х	х	х	х	х	х
	сомі	MAND DAC ADDRESS DAC DATA							DAC DATA														
COMMAND BYTE					DATA HIGH BYTE							DATA LOW BYTE											

Figure 42. Input Shift Register Content

#### **SERIAL OPERATION**

The AD5338R has a 7-bit slave address. The five MSBs are 00011 and the two LSBs (A1 and A0) are set by the state of the A0 and A1 address pins. The ability to make hardwired changes to A0 and A1 allows the user to incorporate up to four of these devices on one bus, as outlined in Table 9.

**Table 9. Device Address Selection** 

A0 Pin Connection	A1 Pin Connection	A0	A1
GND	GND	0	0
$V_{LOGIC}$	GND	1	0
GND	V <sub>LOGIC</sub>	0	1
$V_{LOGIC}$	V <sub>LOGIC</sub>	1	1

The 2-wire serial bus protocol operates as follows:

1. The master initiates data transfer by establishing a start condition when a high-to-low transition on the SDA line occurs while SCL is high. The following byte is the address byte, which consists of the 7-bit slave address. The slave address corresponding to the transmitted address responds by pulling SDA low during the 9<sup>th</sup> clock pulse (this is termed the acknowledge bit). At this stage, all other devices on the bus remain idle while the selected device waits for data to be written to, or read from, its shift register.

- Data is transmitted over the serial bus in sequences of nine clock pulses (eight data bits followed by an acknowledge bit).
   The transitions on the SDA line must occur during the low period of SCL and remain stable during the high period of SCL.
- 3. When all data bits have been read or written, a stop condition is established. In write mode, the master pulls the SDA line high during the 10<sup>th</sup> clock pulse to establish a stop condition. In read mode, the master issues a no acknowledge for the 9<sup>th</sup> clock pulse (that is, the SDA line remains high). The master then brings the SDA line low before the 10<sup>th</sup> clock pulse, and then high during the 10<sup>th</sup> clock pulse to establish a stop condition.

#### **WRITE OPERATION**

When writing to the AD5338R, the user must begin with a start command followed by an address byte ( $R/\overline{W}=0$ ), after which the DAC acknowledges that it is prepared to receive data by pulling SDA low. The AD5338R requires two bytes of data for the DAC and a command byte that controls various DAC functions. Three bytes of data must, therefore, be written to the DAC with the command byte followed by the most significant data byte and the least significant data byte, as shown in Figure 43. All these data bytes are acknowledged by the AD5338R. A stop condition follows.

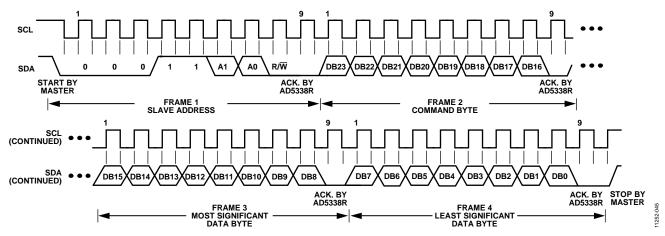


Figure 43. I<sup>2</sup>C Write Operation

#### **READ OPERATION**

When reading data back from the AD5338R DACs, the user begins with an address byte ( $R/\overline{W}=0$ ), after which the DAC acknowledges that it is prepared to receive data by pulling SDA low. This address byte must be followed by the control byte that determines both the read command that is to follow and the pointer address to read from, which is also acknowledged by the DAC. The user configures which channel to read back and sets the readback command to active using the control byte. Following this, there is a repeated start condition by the master and the address is resent with  $R/\overline{W}=1$ . This is acknowledged by the DAC, indicating that it is prepared to transmit data. Two bytes of data are then read from the DAC, as shown in Figure 44. A NACK condition from the master, followed by a STOP condition, completes the read sequence. Default readback is Channel A if both DACs are selected.

#### **MULTIPLE DAC READBACK SEQUENCE**

The user begins with an address byte  $(R/\overline{W} = 0)$ , after which the DAC acknowledges that it is prepared to receive data by pulling SDA low. This address byte must be followed by the control byte, which is also acknowledged by the DAC. The user configures which channel to start the readback using the control byte. Following this, there is a repeated start condition by the master, and the address is resent with  $R/\overline{W} = 1$ . This is acknowledged by the DAC, indicating that it is prepared to transmit data. The first two bytes of data are then read from DAC Input Register A that is selected using the control byte, most significant byte first, as shown in Figure 44. The next four bytes read back are don't care bytes, and the next two bytes of data are the contents of DAC Input Register B. Data continues to be read from the DAC input registers in this auto-incremental fashion, until a NACK followed by a stop condition follows. If the contents of DAC Input Register B are read out, the next bytes of data that are read are from the contents of DAC Input Register A.

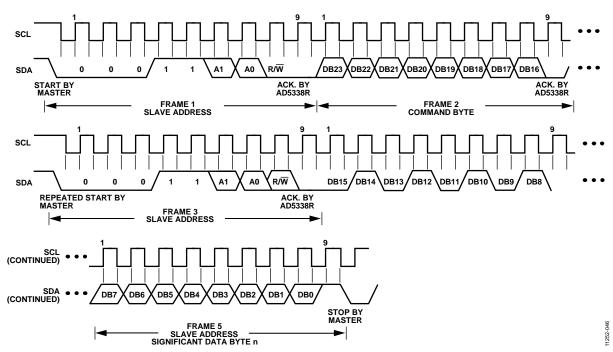


Figure 44. I<sup>2</sup>C Read Operation

#### **POWER-DOWN OPERATION**

The AD5338R contains three separate power-down modes. Command 0100 is designated for the power-down function (see Table 7). These power-down modes are software programmable by setting eight bits, Bit DB7 to Bit DB0, in the shift register. There are two bits associated with each DAC channel. Table 10 shows how the state of the two bits corresponds to the mode of operation of the device.

**Table 10. Modes of Operation** 

Operating Mode	PDx1	PDx0
Normal Operation	0	0
Power-Down Modes		
1 kΩ to GND	0	1
100 k $\Omega$ to GND	1	0
Three-State	1	1

Either or both DACs (DAC A and DAC B) can be powered down to the selected mode by setting the corresponding bits. See Table 11 for the contents of the input shift register during the power-down/ power-up operation.

When both Bit PDx1 and Bit PDx0 (where x is the channel selected) in the input shift register are set to 0, the part works normally with its normal power consumption of 4 mA at 5 V. However, for the three power-down modes, the supply current falls to 4  $\mu A$  at 5 V. Not only does the supply current fall, but also the output stage is also internally switched from the output of

the amplifier to a resistor network of known values. This has the advantage that the output impedance of the part is known while the part is in power-down mode. There are three different power-down options. The output is connected internally to GND through either a 1 k $\Omega$  or a 100 k $\Omega$  resistor, or it is left open-circuited (three-state). The output stage is illustrated in Figure 45.

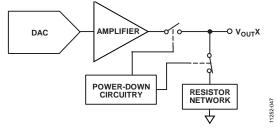


Figure 45. Output Stage During Power-Down

The bias generator, output amplifier, resistor string, and other associated linear circuitry are shut down when the power-down mode is activated. However, the contents of the DAC register are unaffected when in power-down. The DAC register can be updated while the device is in power-down mode. The time required to exit power-down is typically 4.5  $\mu s$  for  $V_{\rm DD}=5~V.$ 

To reduce the current consumption further, the on-chip reference can be powered off. See the Internal Reference Setup section.

Table 11. 24-Bit Input Shift Register Contents of Power-Down/Power-Up Operation<sup>1</sup>

DB23 (MSB)	DB22	DB21	DB20	DB19 to DB16	DB15 to DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0 (LSB)
0	1	0	0	Х	Х	PDB1	PDB0	1	1	1	1	PDA1	PDA0
Con	Command bits (C3 to C0)		Address bits, don't care		Power-Down, select DAC B							-Down, DAC A	

<sup>1</sup> X = don't care.

#### **LOAD DAC (HARDWARE LDAC PIN)**

The AD5338R DACs have double buffered interfaces consisting of two banks of registers: input registers and DAC registers. The user can write to any combination of the input registers. Updates to the DAC register are controlled by the  $\overline{\text{LDAC}}$  pin.

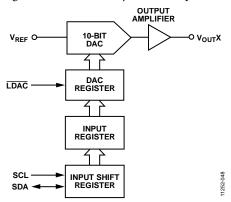


Figure 46. Simplified Diagram of Input Loading Circuitry for a Single DAC

#### Instantaneous DAC Updating (LDAC Held Low)

LDAC is held low while data is clocked into the input register using Command 0001. Both the addressed input register and the DAC register are updated on the 24<sup>th</sup> clock, and the output begins to change (see Table 14).

#### Deferred DAC Updating (LDAC is Pulsed Low)

LDAC is held high while data is clocked into the input register using Command 0001. Both DAC outputs are asynchronously updated by taking  $\overline{\text{LDAC}}$  low after the 24<sup>th</sup> clock. The update now occurs on the falling edge of  $\overline{\text{LDAC}}$ .

#### **LDAC MASK REGISTER**

Command 0101 is reserved for this software  $\overline{LDAC}$  mask function, which allows the address bits to be ignored. Writing to the DAC using Command 0101, loads the 4-bit  $\overline{LDAC}$  register (DB3 to DB0). The default for each channel is 0; that is, the  $\overline{LDAC}$  pin works normally. Setting the bits to 1 forces this DAC channel to ignore transitions on the  $\overline{LDAC}$  pin, regardless of the state of the hardware  $\overline{LDAC}$  pin. This flexibility is useful in applications where the user wishes to select which channels respond to the  $\overline{LDAC}$  pin.

Table 12. LDAC Overwrite Definition

Load LDAC	Register	
LDAC Bits (DB3 or DB0)	LDAC Pin	LDAC Operation
0	1 or 0	Determined by the LDAC pin.
1	X <sup>1</sup>	DAC channels <u>update</u> and override the <u>LDAC</u> pin. DAC channels see <u>LDAC</u> pin as 1.

 $<sup>^{1}</sup>$  X = don't care.

The  $\overline{LDAC}$  register gives the user extra flexibility and control over the hardware  $\overline{LDAC}$  pin (see Table 12). Setting the  $\overline{LDAC}$  bits (DB0 or DB3) to 0 for a DAC channel means that the update of the channel is controlled by the hardware  $\overline{LDAC}$  pin.

Table 13. 24-Bit Input Shift Register Contents for LDAC Operation<sup>1</sup>

DB23 (MSB)	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DBB15 to DB4	DB3	DB2	DB1	DB0 (LSB)
0	0	0	1	Χ	Χ	Χ	Х	Х	DAC B	0	0	DAC A
Command bits (C3 to C0)			Address bits, don't care			Don't care	Setteing LDAC to 1 overrides the LDAC pin			ides		

<sup>&</sup>lt;sup>1</sup> X = don't care.

Table 14. Write Commands and LDAC Pin Truth Table 1

		Hardware LDAC	Input Register	
Command	Description	Pin State	Contents	DAC Register Contents
0001	Write to Input Register n (dependent on LDAC)	V <sub>LOGIC</sub>	Data update	No change (no update)
		GND <sup>2</sup>	Data update	Data update
0010	Update DAC Register n with contents of	V <sub>LOGIC</sub>	No change	Updated with input register contents
	Input Register n	GND	No change	Updated with input register contents
0011	Write to and update DAC Channel n	V <sub>LOGIC</sub>	Data update	Data update
		GND	Data update	Data update

A high-to-low hardware LDAC pin transition always updates the contents of the DAC register with the contents of the input register on channels that are not masked (blocked) by the LDAC mask register.

 $<sup>^2</sup>$  When the  $\overline{\text{LDAC}}$  pin is permanently tied low, the  $\overline{\text{LDAC}}$  mask bits are ignored.

#### HARDWARE RESET (RESET)

RESET is an active low reset that allows the outputs to be cleared to either zero scale or midscale. The clear code value is user selectable via the power-on reset select (RSTSEL) pin. It is necessary to keep RESET low for a minimum amount of time to complete the operation. When the RESET signal is returned high, the output remains at the cleared value until a new value is programmed. The outputs cannot be updated with a new value while the RESET pin is low. Also, a software executable reset function can reset the DAC to the power-on reset code. Command 0110 is designated for this software reset function (see Table 7). Any events on LDAC during a power-on reset are ignored. If the RESET pin is pulled low at power-up, the device does not initialize correctly until the pin is released.

#### **RESET SELECT PIN (RSTSEL)**

The AD5338R contains a power-on reset circuit that controls the output voltage during power-up. By connecting the RSTSEL pin low, the output powers up to zero scale. Note that this is outside the linear region of the DAC; by connecting the RSTSEL pin high, V<sub>OUT</sub> powers up to midscale. The output remains powered up at this level until a valid write sequence is made to the DAC.

#### INTERNAL REFERENCE SETUP

Command 0111 is reserved for setting up the internal reference (see Table 7). By default, the on-chip reference is on at power-up. To reduce the supply current, this reference can be turned off by setting the software-programmable bit, DB0, as shown in Table 16. Table 15 shows how the state of the bit corresponds to the mode of operation.

**Table 15. Reference Setup Register** 

Internal Reference Setup Register (DB0)	Action
0	Reference on (default)
1	Reference off

#### **SOLDER HEAT REFLOW**

As with all IC reference voltage circuits, the reference value experiences a shift induced by the soldering process. Analog Devices, Inc., performs a reliability test called precondition to mimic the effect of soldering a device to a board. The output

voltage specification quoted in Table 3 includes the effect of this reliability test.

Figure 47 shows the effect of solder heat reflow (SHR) as measured through the reliability test (precondition).

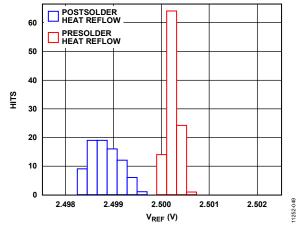


Figure 47. SHR Reference Voltage Shift

#### **LONG-TERM TEMPERATURE DRIFT**

Figure 48 shows the change in the  $V_{\text{REF}}$  (ppm) value after 1000 hours at 25°C ambient temperature.

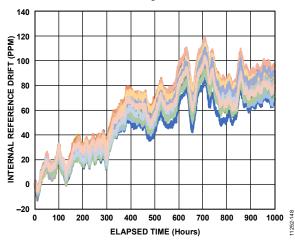


Figure 48. Reference Drift Through to 1000 Hours

Table 16. 24-Bit Input Shift Register Contents for Internal Reference Setup Command<sup>1</sup>

DB23 (MSB)	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15 to DB1	DB0 (LSB)
0	1	1	1	Х	Х	Χ	Χ	Х	0/1
Command bits (C3 to C0)			Address bits (A3 to A0)				Don't care	Reference setup register	

<sup>1</sup> X = don't care.

#### **THERMAL HYSTERESIS**

Thermal hysteresis is the voltage difference induced on the reference voltage by sweeping the temperature from ambient to cold, to hot, and then back to ambient.

Thermal hysteresis data is shown in Figure 49. It is measured by sweeping temperature from ambient to  $-40^{\circ}$ C, then to  $+105^{\circ}$ C, and returning to ambient. The  $V_{\text{REF}}$  delta is then measured between the two ambient measurements and shown in blue in Figure 49. The same temperature sweep and measurements are immediately repeated, and the results are shown in red in Figure 49.

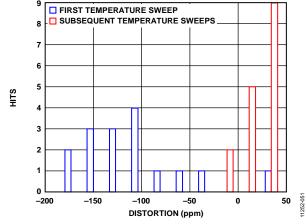


Figure 49. Thermal Hysteresis

# APPLICATIONS INFORMATION MICROPROCESSOR INTERFACING

Microprocessor interfacing to the AD5338R is via a serial bus that uses a standard protocol that is compatible with DSP processors and microcontrollers. The communications channel requires a 2-wire interface consisting of a clock signal and a data signal.

#### AD5338R TO ADSP-BF531 INTERFACE

The I<sup>2</sup>C interface of the AD5338R is designed to be easily connected to industry-standard DSPs and microcontrollers. Figure 50 shows the AD5338R connected to the Analog Devices Blackfin® DSP (ADSP-BF531). The Blackfin has an integrated I<sup>2</sup>C port that can be connected directly to the I<sup>2</sup>C pins of the AD5338R.

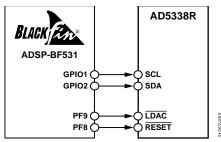


Figure 50. ADSP-BF531 Interface to the AD5338R

#### **LAYOUT GUIDELINES**

In any circuit where accuracy is important, careful consideration of the power supply and ground return layout helps to ensure the rated performance. Design the printed circuit board (PCB) on which the AD5338R is mounted so that the AD5338R lies on the analog plane.

The AD5338R must have ample supply bypassing of 10  $\mu F$  in parallel with 0.1  $\mu F$  on each supply, located as close to the package as possible, ideally right up against the device. The 10  $\mu F$  capacitor is the tantalum bead type. The 0.1  $\mu F$  capacitor must have low effective series resistance (ESR) and low effective series inductance (ESI), such as the common ceramic types that provide a low impedance path to ground at high frequencies to handle transient currents due to internal logic switching.

In systems where there are many devices on one board, it is often useful to provide some heat sinking capability to allow the power to dissipate easily.

The AD5338R LFCSP model has an exposed paddle beneath the device. Connect this paddle to the GND supply for the part. For optimum performance, use special considerations to design the motherboard and to mount the package. For enhanced thermal, electrical, and board level performance, solder the exposed paddle on the bottom of the package to the corresponding thermal land paddle on the PCB. Design thermal vias into the PCB land paddle area to further improve heat dissipation.

The GND plane on the device can be increased (as shown in Figure 51) to provide a natural heat sinking effect.

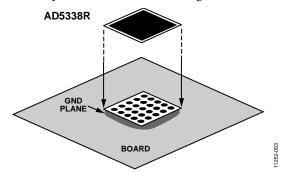
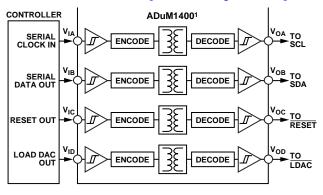


Figure 51. Paddle Connection to Board

#### **GALVANICALLY ISOLATED INTERFACE**

In many process control applications, it is necessary to provide an isolation barrier between the controller and the unit being controlled to protect and isolate the controlling circuitry from any hazardous common-mode voltages that may occur. *i*Coupler\* products from Analog Devices provide voltage isolation in excess of 2.5 kV. The serial loading structure of the AD5338R makes the part ideal for isolated interfaces because the number of interface lines is kept to a minimum. Figure 52 shows a 4-channel isolated interface to the AD5338R using the ADuM1400. For further information, visit http://www.analog.com/iCouplers.



<sup>1</sup>ADDITIONAL PINS OMITTED FOR CLARITY.

Figure 52. Isolated Interface

11252-054

# **OUTLINE DIMENSIONS**

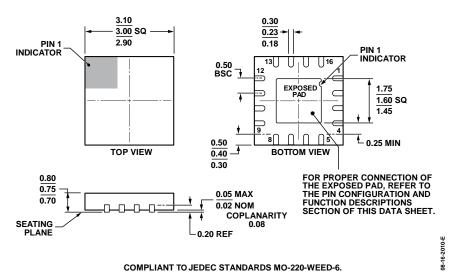
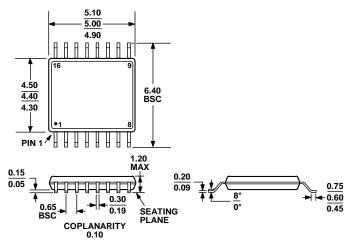


Figure 53. 16-Lead Lead Frame Chip Scale Package [LFCSP\_WQ] 3 mm × 3 mm Body, Very Very Thin Quad (CP-16-22) Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-153-AB

Figure 54. 16-Lead Thin Shrink Small Outline Package [TSSOP] (RU-16) Dimensions shown in millimeters

#### **ORDERING GUIDE**

Model <sup>1</sup>	Resolution	Temperature Range	Accuracy	Reference Temperature Coefficient (ppm/°C)	Package Description	Package Option	Branding
AD5338RBCPZ-RL7	10 Bits	-40°C to +105°C	±1 LSB INL	±5 (max)	16-Lead LFCSP_WQ	CP-16-22	DKX
AD5338RBRUZ	10 Bits	-40°C to +105°C	±1 LSB INL	±5 (max)	16-Lead TSSOP	RU-16	
AD5338RBRUZ-RL7	10 Bits	-40°C to +105°C	±1 LSB INL	±5 (max)	16-Lead TSSOP	RU-16	
EVAL-AD5338RDBZ					Evaluation Board		

<sup>&</sup>lt;sup>1</sup> Z = RoHS Compliant Part.

# **NOTES**



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